

DSD HW2 Single-cycle RISCV Processor

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Date: 2024/03/28

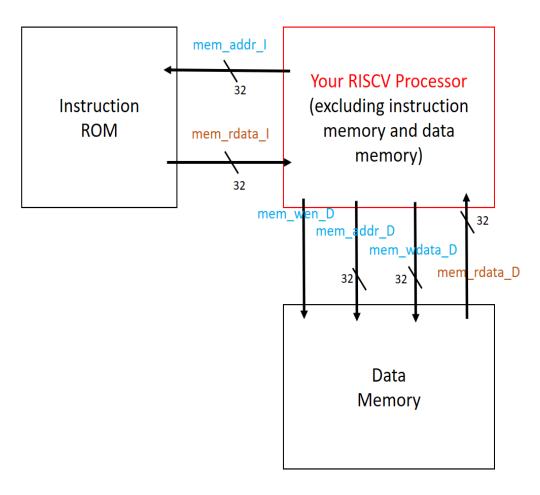


Problem Statement

- Using Verilog, implement the single-cycle RISC-V processor:
 - Supported instructions:
 - > add, sub, and, or, slt
 - ➤ Iw, sw
 - > beq
 - jal, jalr
- Testbench/Memory models are provided
 - Hidden testbench are not provided



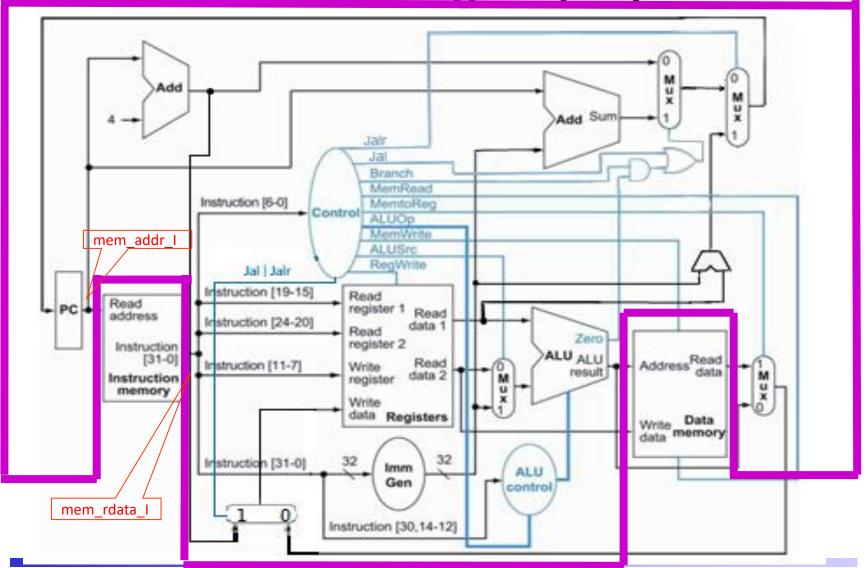
Block Diagram(1/2)



- Instruction ROM: contains the testing instructions
- Data Memory:contains the stored dataUsed for testing your circuit
 - mem_wen_D: mem_wen_D is high, writing data to D-mem when the next clk arrive; else reading data from memory to chip.



Block Diagram(2/2)





Testbench

- The testbench will
 - Initialize the instruction rom and the data memory
 - Reset your circuit
 - Execute the instructions, and check the values stored in data memory to see whether your circuit is correct
 - If your function is correct, you will see the following



Clock/Reset/Register File

- Clock: positive edge triggered
- Reset: active low synchronous reset
- Register file
 - All registers are reset to 0 when reset occurs
 - Register x0 must be always 0
- There is no endianness issue!
 - If you store 32'h12345678 in x8, RF_8_w[31:0] = 32'h12345678



Memory Layout

Instruction memory for RISC-V

```
03_24_00_00 // 0000000000000_00000_010_01000_0000011
83_24_40_00 // 000000000100_00000_010_01001_0000011
33_04_84_00 // 0000000_01000_01000_000_01000_0110011
33_05_94_40 // 0100000_01001_01000_000_01010_0110011
```

Data memory for RISC-V

```
0F_00_00_00 // 0x0000000F
14_00_00_00 // 0x00000014
00_00_00_00
00_00_00
```

- Conversion between big/little-endian
 - \diamond out[31:0] = {in[7:0], in[15:8], in[23:16], in[31:24]};



Memory

- Instruction ROM and data memory are included in the testbench
- As for data memory
 - 32 words x 32 bits
 - The input signal mem_wen_D is high, writing data to D-mem when the next clk arrive; else reading data from memory to chip.

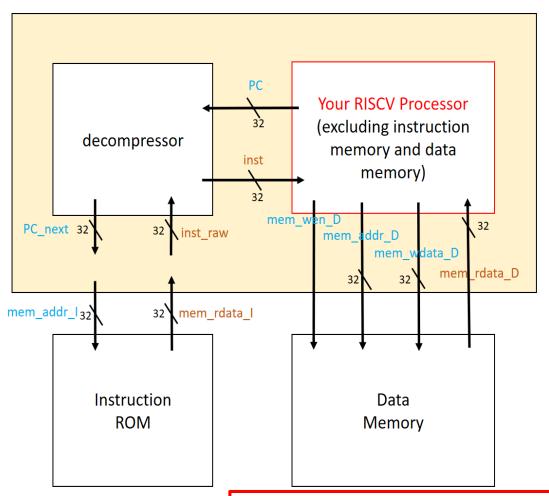


Memory Addressing

- In RISCV, the memory address is byte address.
- In Instruction ROM and data memory, the memory address is word address.
- Both the memory size of Instruction ROM and data memory in this work are 32x32, so their input address is 5-bit wide.
 - You are encouraged to observe the connection between each module in RISCV_tb.v.



Block Diagram



- Instruction ROM: contains the testing instructions
- Data Memory: contains the stored data
 - Used for testing your circuit
- decompressor:
 - Resolve the raw inst. from I-ROM and output the correct mem_rdata_I to CHIP
 - Maintain the PC and output the correct address to fetch inst. from I-ROM

No decompressor in HW2!



Simulation & Synthesis

- Check "RISCV/ verilog/ readme.txt"
- 3 Major Things
 - RTL coding & simulation
 - Logic Synthesis
 - Gate-level simulation & debugging/refinement
- Files needed for simulation
 - * RTL code: CHIP.v
 - Gate-level code: CHIP_syn.v
 - Timing info (SDF file): CHIP_syn.sdf
 - Design library (DDC file): CHIP_syn.ddc



XNotice

- 1. Latches are not allowed in gate level code after synthesis, use Flip-flop instead.
- Negative Slack and Timing Violations are not allowed after synthesis.
- 3. The tsmc13.v file is not allowed to be downloaded! Or you may offend the copyright protected by NTU & CIC!



Grading Policy

- * RTL (40%): function correctness
 - 10% for hidden testbench
- Synthesis (30%): correctness
 - 10% for hidden testbench
- * Report (20%)
- Area*Timing (10%)
 - Passing all testbenches will rank higher than passing the provided testbench only
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Report

1. Simulated timing (ns)

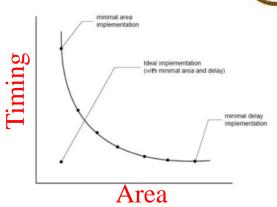
Gate-level simulation clock cycle
 (i.e. The cycle you passed testbench after synthesis)



- report_area
- 3. Cost (A*T)
 - Area*Gate-level simulation clock cycle

4. ScreenShot

Inferred memory devices in process (*No latch should be inferred!)



```
172
                                            367
Number of nets:
                                            130
       of combinational cells:
                                            125
 umber of sequential cells:
                                              0
                                              0
                                             39
umber of buf/inv:
                                             22
Number of references:
Combinational area:
                           43665.613947
loncombinational area:
                           32960.112083
let Interconnect area:
                             undefined (No wire load specified)
Total cell area:
                           76625.726031
Total area:
```



Submission(1/2)

- You need to submit 4 files + 1 report
 - * RTL code: CHIP.v
 - Synthesis:

```
CHIP_syn.v,
CHIP_syn.sdf,
CHIP_syn.ddc
```

- Report: report.pdf
- Compress all the files into one ZIP file
 - ❖ File name: DSD_HW2_學號.zip
 - ❖ EX: DSD_HW2_b10901001.zip
- Upload the file to NTUCOOL
- Deadline: 2024/04/17 23:59
- Late submission penalty: 20% per day



Submission(2/2)

```
❖ DSD_HW2_學號/

RISCV/

CHIP.v

CHIP_syn.v

CHIP_syn.sdf

CHIP_syn.ddc

report.pdf
```



Appendix A

- Why Little endian?
 - Fetch with the same address if a given value is stored in different width
 - > 32bit 0x0D0C0B0A
 - > 64bit 0x000000000D0C0B0A
 - ➤ We can always fetch the lowest 32bit address
 - Mainstream
 - ➤ Intel x86

